

# EE 230

## Lecture 33

Small Signal Operation of Nonlinear  
Networks

# Quiz 33

Assume a one-port device has an I-V relationship given by the equation

$$I = 5V^2$$

Determine the small-signal model of this device at  $V=2V$ .

And the number is ?

1

3

8

5

4

?

2

6

9

7

# Quiz 33

Assume a one-port device has an I-V relationship given by the equation

$$I = 5V^2$$

Determine the small-signal model of this device at  $V=2V$ .

*Solution:*

$$i_{ss} = \left. \frac{\partial I}{\partial V} \right|_{V=V_Q} v_{ss}$$

$$\left. \frac{\partial I}{\partial V} \right|_{V=V_Q} = 10V \Big|_{V=2V} = 20AV^{-1}$$

*Small signal model that of a conductor of value  $20AV^{-1}$*

Review from Last Time:

# Methods of Analysis of Nonlinear Circuits

Will consider three different analysis requirements and techniques for some particularly common classes of nonlinear circuits

## 1. Circuits with continuously differential devices

Interested in obtaining transfer characteristics of these circuits or outputs for given input signals

## 2. Circuits with piecewise continuous devices

interested in obtaining transfer characteristics of these circuits or outputs for a given input signals

## → 3. Circuits with small-signal inputs that vary around some operating point

Interested in obtaining relationship between small-signal inputs and the corresponding small-signal outputs. Will assume these circuits operate linearly in some suitably small region around the operating point

Other types of nonlinearities may exist and other types of analysis may be required but we will not attempt to categorize these scenarios in this course

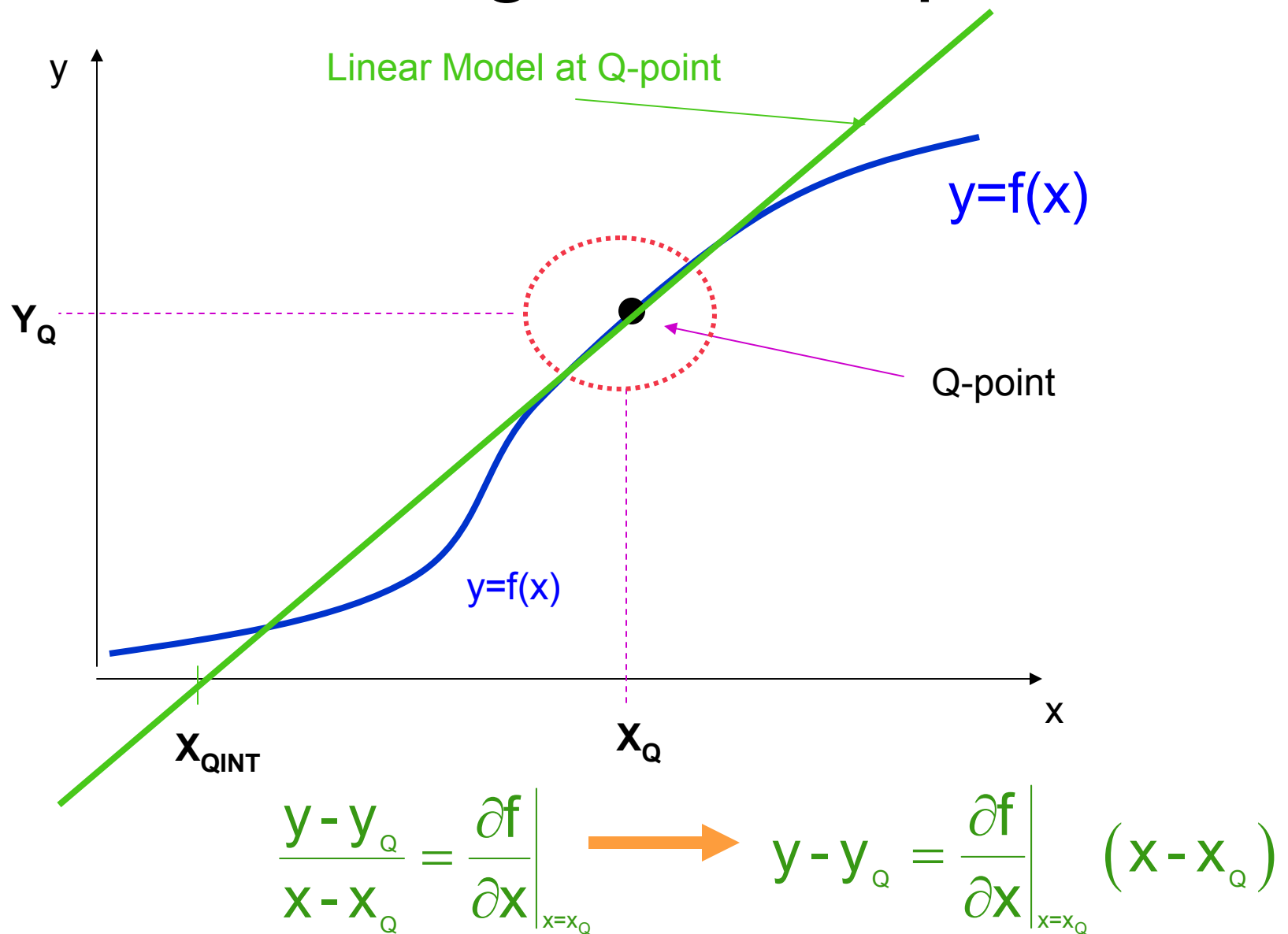
Review from Last Time:

## Circuits with small-signal inputs that vary around some operating point

- *This is one of the most useful classes of circuits that exist*
- *Use is driven by goal to use nonlinear devices ( at fundamental device level, that's all we have that provide power gain) to perform linear signal processing functions*
- *Concept of “systems” with small-signal inputs that vary around some operating point throughout the electrical engineering field and in many other fields as well*
- *Although the concepts will be introduced in the context of electronic circuits, the principles and mathematics are generally applied*

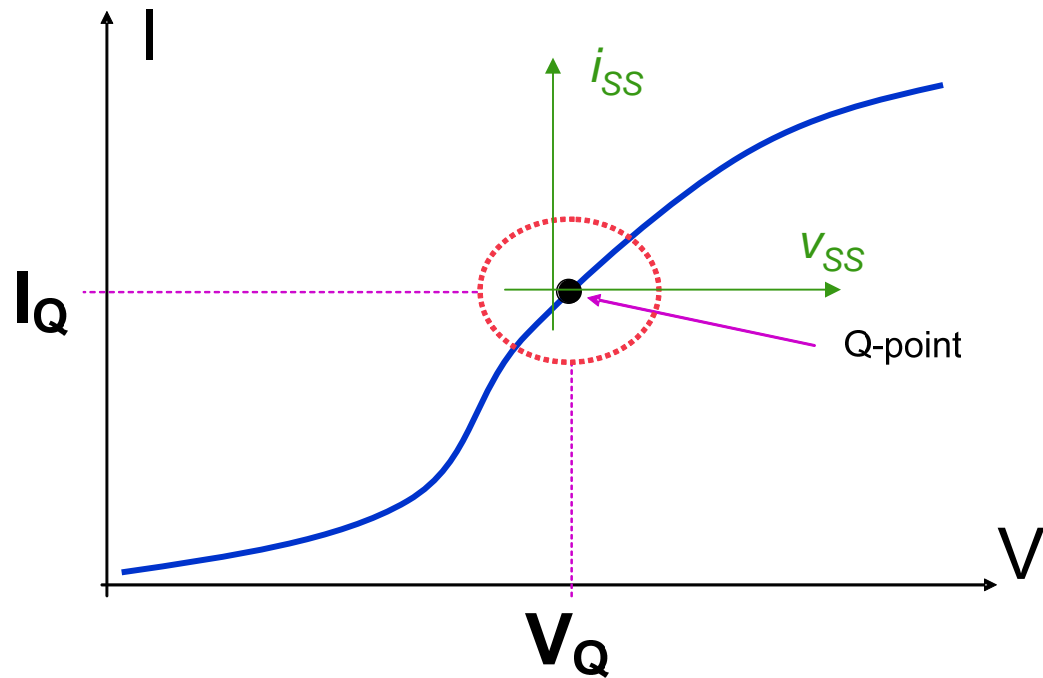
Review from Last Time:

# Small-Signal Principle



Review from Last Time:

# Small-Signal Principle



$$i_{ss} = \left. \frac{\partial I}{\partial V} \right|_{V=V_Q} v_{ss}$$

$$i_{ss} \stackrel{\text{def}}{=} i$$

$$v_{ss} \stackrel{\text{def}}{=} v$$

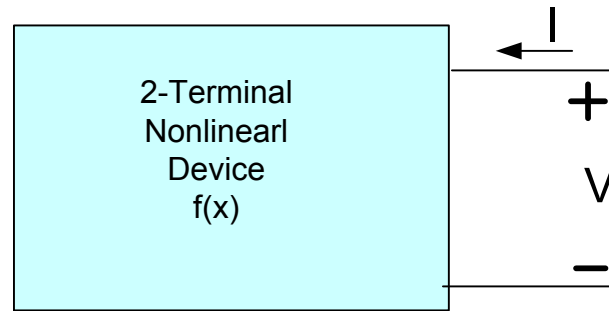
$$y \stackrel{\text{defn}}{=} \left. \frac{\partial I}{\partial V} \right|_{V=V_Q}$$

$$i = y v$$



Review from Last Time:

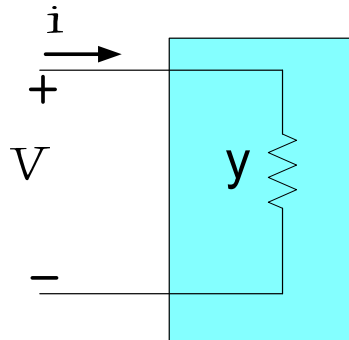
# Small-Signal Principle



$$y = \left. \frac{\partial I}{\partial V} \right|_{V=V_Q}$$

$$i = y v$$

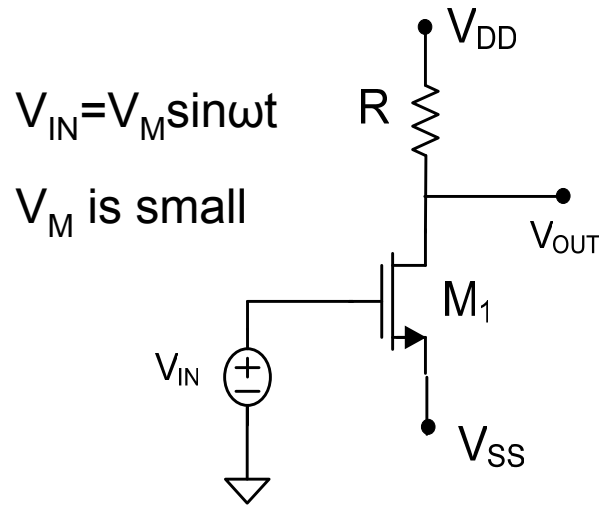
A Small Signal Equivalent Circuit



*The small-signal model of this 2-terminal electrical network is a resistor of value  $1/y$   
One small-signal parameter characterizes this one-port but it is dependent on Q-point*

Review from Last Time:

## Small signal analysis example



$$V_{OUT} = V_{DD} - \frac{\mu C_{OX} W}{2L} (V_M \sin \omega t - [V_{SS} + V_T])^2 R$$

$$V_{OUT} = V_{DD} - \frac{\mu C_{OX} W}{2L} [V_{SS} + V_T]^2 \left( 1 - \frac{V_M \sin \omega t}{[V_{SS} + V_T]} \right)^2 R$$

Recall that if  $x$  is small  $(1+x)^2 \cong 1+2x$

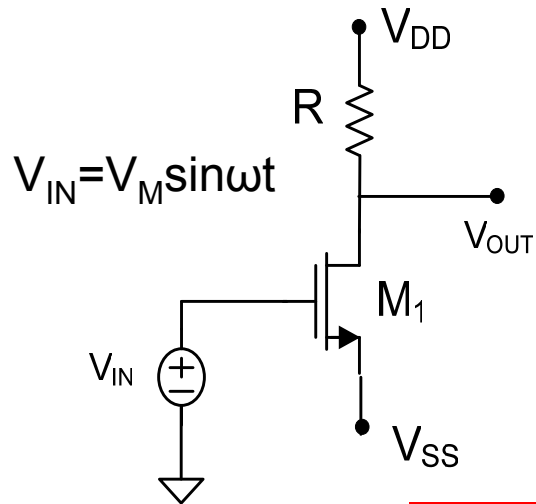
$$V_{OUT} = V_{DD} - \frac{\mu C_{OX} W}{2L} [V_{SS} + V_T]^2 \left( 1 - \frac{2V_M \sin \omega t}{[V_{SS} + V_T]} \right) R$$

$$V_{OUT} = \left\{ V_{DD} - \frac{\mu C_{OX} W}{2L} [V_{SS} + V_T]^2 R \right\} + \frac{\mu C_{OX} W}{2L} [V_{SS} + V_T]^2 \left( \frac{2V_M \sin \omega t}{[V_{SS} + V_T]} \right) R$$

$$V_{OUT} = \left\{ V_{DD} - \frac{\mu C_{OX} W}{2L} [V_{SS} + V_T]^2 R \right\} + \left\{ \frac{\mu C_{OX} W}{L} [V_{SS} + V_T] R \right\} V_M \sin \omega t$$

Review from Last Time:

## Small signal analysis example



Assume  $M_1$  operating in saturation region

$$V_{OUT} = \left\{ V_{DD} - \frac{\mu C_{ox} W}{2L} [V_{SS} + V_T]^2 R \right\} + \left\{ \frac{\mu C_{ox} W}{L} [V_{SS} + V_T] R \right\} V_M \sin \omega t$$

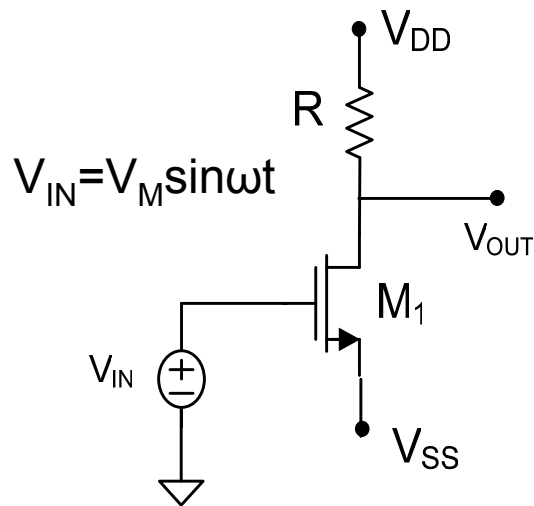
*Quiescent Output*                      *ss Voltage Gain*

$$A_v = \frac{\mu C_{ox} W}{L} [V_{SS} + V_T] R$$

*But – this expression gives little insight into how large the gain is !*

Review from Last Time:

## Small signal analysis example



$$A_v = \frac{2I_{DQ} R}{[V_{SS} + V_T]}$$

*Observe the small signal voltage gain is twice the Quiescent voltage across  $R$  divided by  $V_{SS} + V_T$*

If  $V_{SS}$  and  $R$  are chosen properly, this inverting gain can be quite large!

- This analysis which required linearization of a nonlinear output voltage is quite tedious.
- This approach becomes unwieldy for even slightly more complicated circuits
- A much easier approach based upon the development of small signal models will provide the same results, provide more insight into both analysis and design, and result in a dramatic reduction in computational requirements

# Small-signal Operation of Nonlinear Circuits

- Small-signal principles
- Example Circuit
- Small-Signal Models
- Small-Signal Analysis of Nonlinear Circuits

*Solution for the example was based upon solving the nonlinear circuit for  $V_{OUT}$  and then linearizing the solution by doing a Taylor's series expansion*

- Solution of nonlinear equations very involved with two or more nonlinear devices*
- Taylor's series linearization can get very tedious if multiple nonlinear devices are present*

**Brute Force Approach to small-signal analysis of nonlinear networks**

- 1. Solve nonlinear network*
- 2. Linearize solution*

**Alternative Approach to small-signal analysis of nonlinear networks**

- 1. Linearize nonlinear devices*
- 2. Replace **all** devices with small-signal equivalent (linear)*
- 3. Solve linear small-signal network*

## Alternative Approach to small-signal analysis of nonlinear networks

1. *Linearize nonlinear devices* (linear devices already linear)
2. *Replace all devices with small-signal equivalent*
3. *Solve linear small-signal network*

- **Must only develop linearized model once for any nonlinear device**

*e.g. once for a MOSFET, once for a JFET, and once for a BJT*

*Linearized model for nonlinear device termed “small-signal model”*

*derivation of small-signal model for most nonlinear devices is less complicated than solving even one simple nonlinear circuit*

- **Solution of linear network much easier than solution of nonlinear network**

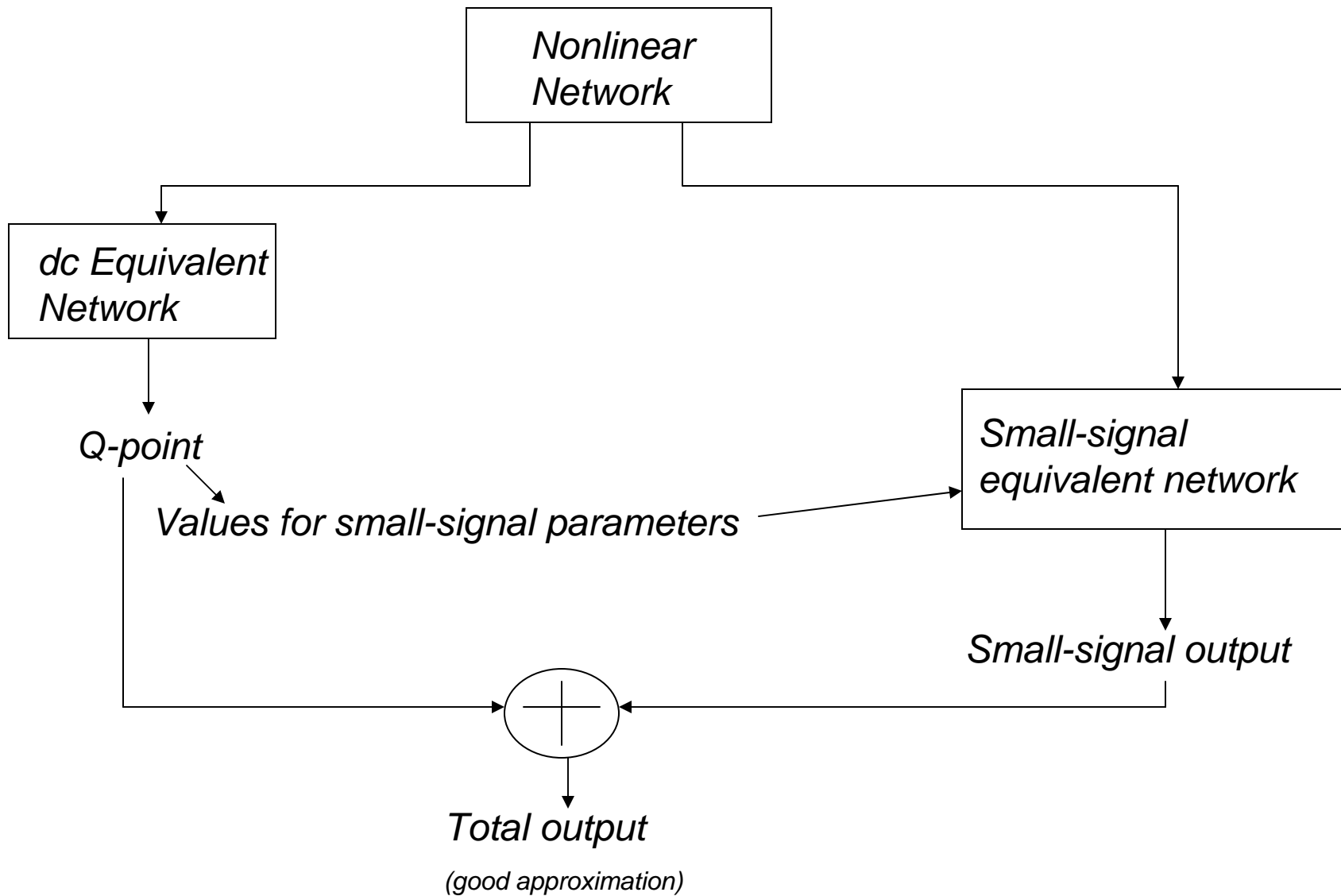
The alternative approach has become the standard approach for analyzing nonlinear networks with small-signal inputs

## **Standard Approach to small-signal analysis of nonlinear networks**

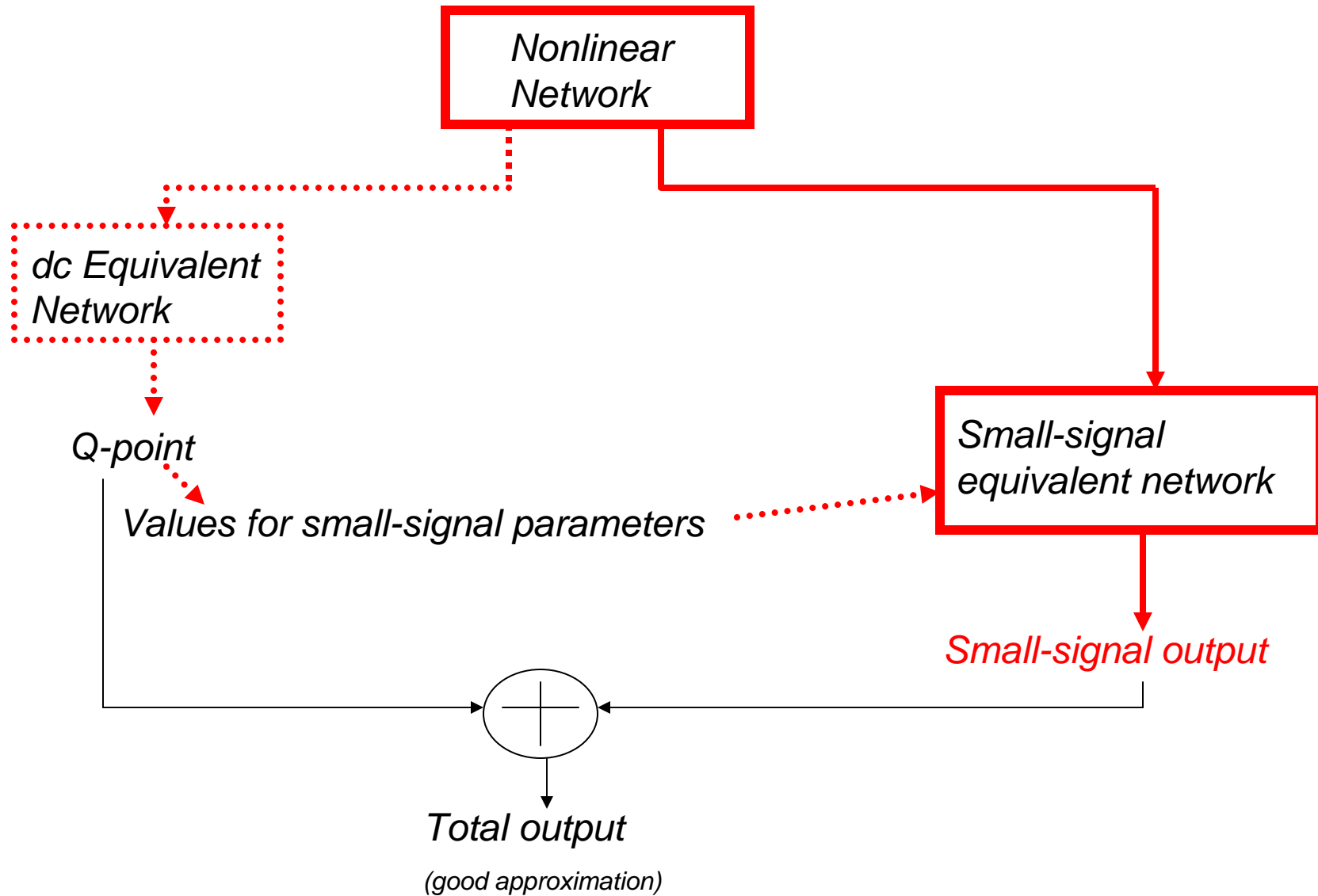
1. *Linearize nonlinear devices*
2. *Replace all devices with small-signal equivalent*
3. *Solve linear small-signal network*



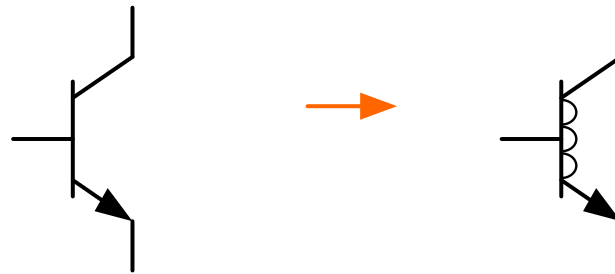
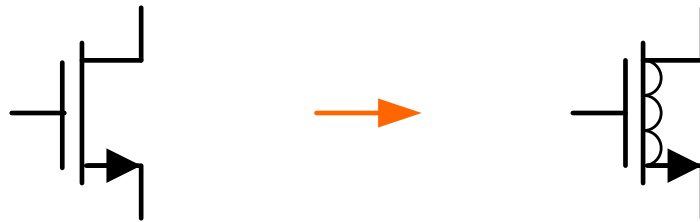
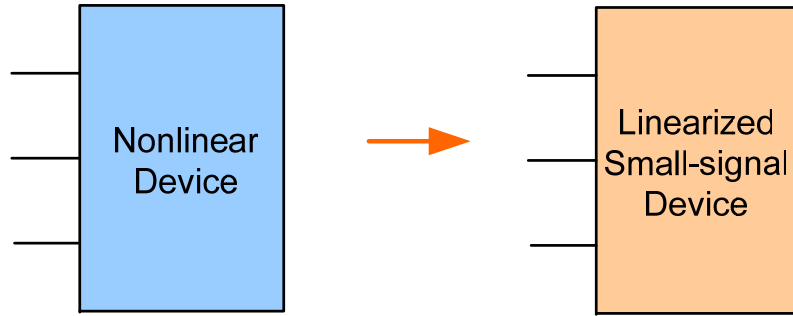
# Standard Approach to analysis of nonlinear networks



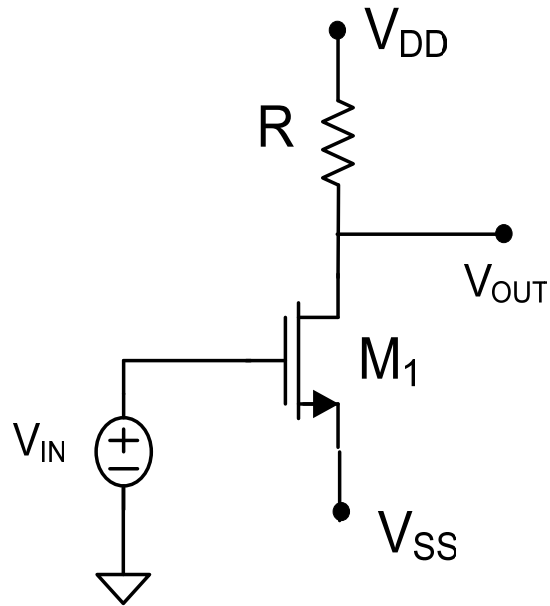
# Standard Approach to small-signal analysis of nonlinear networks



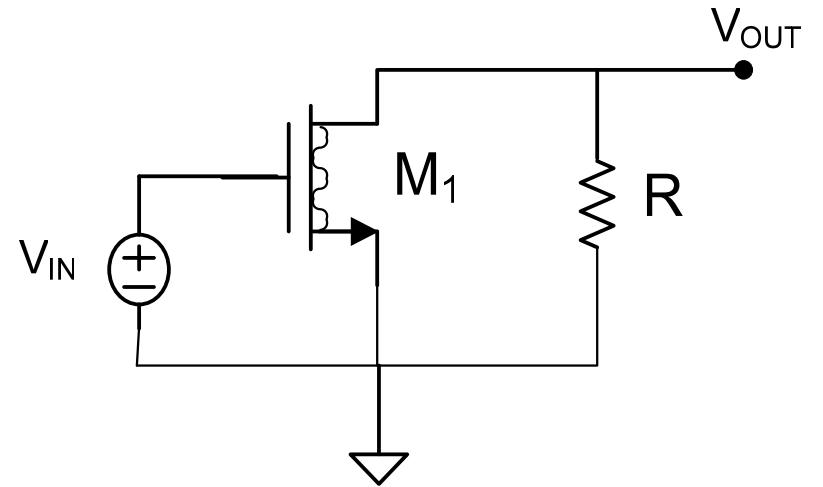
*Linearized nonlinear devices*



*Example: (will provide justification later)*


















*Nonlinear network*

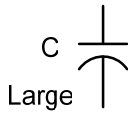


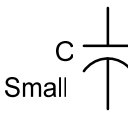
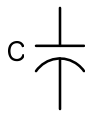

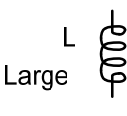


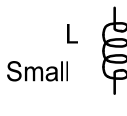
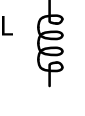


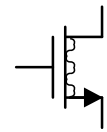
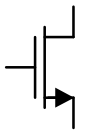
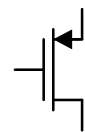
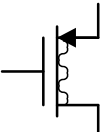
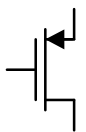


*Linearized small-signal network*

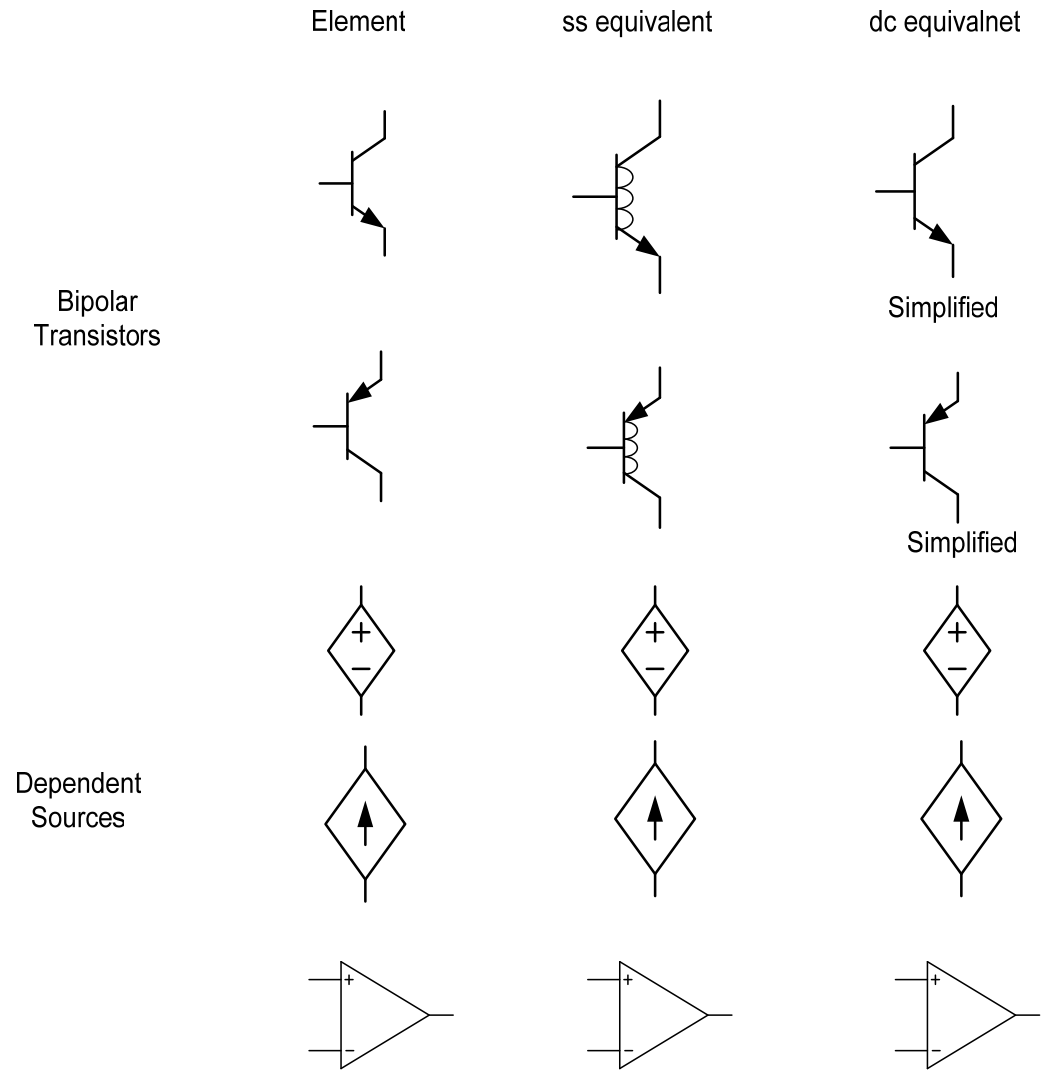
# Dc and small-signal equivalent elements

	Element	ss equivalent	dc equivalent
dc Voltage Source	$V_{DC}$ 		$V_{DC}$ 
ac Voltage Source	$V_{AC}$ 	$V_{AC}$ 	
dc Current Source	$I_{DC}$ 		$I_{DC}$ 
ac Current Source	$I_{AC}$ 	$I_{AC}$ 	
Resistor	$R$ 	$R$ 	$R$ 

# Dc and small-signal equivalent elements

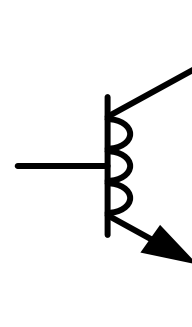
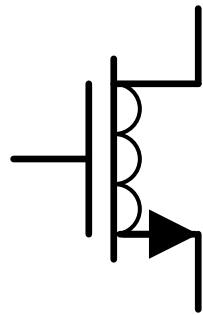
	Element	ss equivalent	dc equivalent
Capacitors	<p>C</p> <p>Large</p> 		
	<p>C</p> <p>Small</p> 	<p>C</p> 	
Inductors	<p>L</p> <p>Large</p> 		
	<p>L</p> <p>Small</p> 	<p>L</p> 	
MOS Transistors			 <p>Simplified</p>
			 <p>Simplified</p>

# Dc and small-signal equivalent elements



How is the small-signal equivalent circuit obtained from the nonlinear circuit?

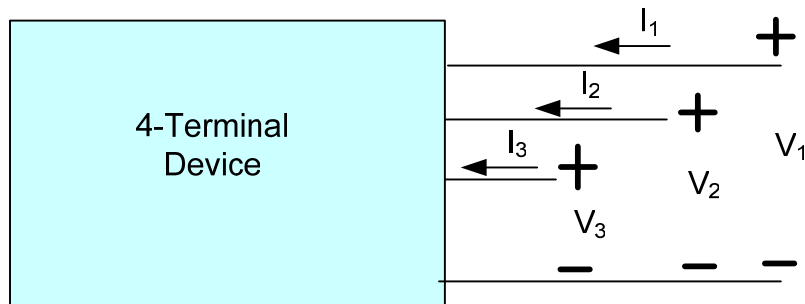
*What is the small-signal equivalent of the MOSFET and BJT ?*





# Small-Signal Model

Consider 4-terminal network



$$\left. \begin{aligned} I_1 &= f_1(V_1, V_2, V_3) \\ I_2 &= f_2(V_1, V_2, V_3) \\ I_3 &= f_3(V_1, V_2, V_3) \end{aligned} \right\}$$

Define

$$i_1 = I_1 - I_{1Q}$$

$$i_2 = I_2 - I_{2Q}$$

$$i_3 = I_3 - I_{3Q}$$

$$u_1 = V_1 - V_{1Q}$$

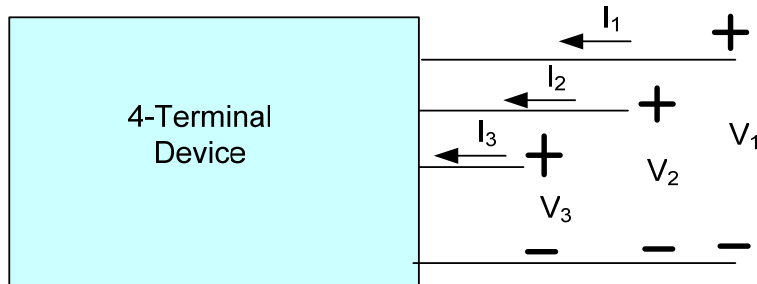
$$u_2 = V_2 - V_{2Q}$$

$$u_3 = V_3 - V_{3Q}$$

Small signal model is that which represents the relationship between the small signal voltages and the small signal currents

# Small-Signal Model

Consider 4-terminal network



$$\left. \begin{aligned} i_1 &= g_1(v_1, v_2, v_3) \\ i_2 &= g_2(v_1, v_2, v_3) \\ i_3 &= g_3(v_1, v_2, v_3) \end{aligned} \right\}$$

Small signal model is that which represents the relationship between the small signal voltages and the small signal currents

For small signals, this relationship should be linear

Can be thought of as a change in coordinate systems from the large signal coordinate system to the small-signal coordinate system

# Recall for a function of one variable

$$y = f(x)$$

Taylor's Series Expansion about the point  $x_0$

$$y = f(x) = f(x)|_{x=x_0} + \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0) + \left. \frac{\partial^2 f}{\partial x^2} \right|_{x=x_0} \frac{1}{2!} (x - x_0)^2 + \dots$$

If  $x - x_0$  is small

$$y \cong f(x)|_{x=x_0} + \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0)$$

$$y \cong y_0 + \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0)$$

# Recall for a function of one variable

$$y = f(x)$$

If  $x - x_0$  is small

$$y \cong y_0 + \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0)$$

$$y - y_0 = \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0)$$

If we define the small signal variables as

$$\boldsymbol{y} = y - y_0$$

$$\boldsymbol{x} = x - x_0$$

# Recall for a function of one variable

$$y = f(x)$$

If  $x - x_0$  is small

$$y - y_0 = \left. \frac{\partial f}{\partial x} \right|_{x=x_0} (x - x_0)$$

If we define the small signal variables as

$$\mathbf{y} = y - y_0$$

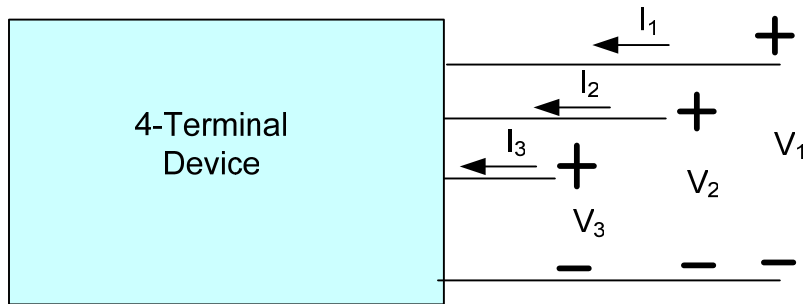
$$\mathbf{x} = x - x_0$$

Then

$$\mathbf{y} = \left. \frac{\partial f}{\partial x} \right|_{x=x_0} \mathbf{x}$$

This relationship is linear !

## Consider 4-terminal network



$$\left. \begin{aligned} \mathbf{I}_1 &= \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{I}_2 &= \mathbf{f}_2(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{I}_3 &= \mathbf{f}_3(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \end{aligned} \right\}$$

Nonlinear network characterized by 3 functions each functions of 3 variables

Consider now 3 functions each functions of 3 variables

$$\left. \begin{aligned} \mathbf{l}_1 &= \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{l}_2 &= \mathbf{f}_2(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{l}_3 &= \mathbf{f}_3(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \end{aligned} \right\}$$

Define

$$\bar{\mathbf{V}}_Q = \begin{bmatrix} V_{1Q} \\ V_{2Q} \\ V_{3Q} \end{bmatrix}$$

Consider now 3 functions each functions of 3 variables

$$\left. \begin{aligned}
 \mathbf{I}_1 &= \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\
 \mathbf{I}_2 &= \mathbf{f}_2(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\
 \mathbf{I}_3 &= \mathbf{f}_3(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)
 \end{aligned} \right\} \text{ Define } \bar{\mathbf{V}}_Q = \begin{bmatrix} \mathbf{V}_{1Q} \\ \mathbf{V}_{2Q} \\ \mathbf{V}_{3Q} \end{bmatrix}$$

$$\mathbf{I}_1 = \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \cong \mathbf{f}_1(\mathbf{V}_{1Q}, \mathbf{V}_{2Q}, \mathbf{V}_{3Q}) + \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_1} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_1 - \mathbf{V}_{1Q}) + \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_2} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_2 - \mathbf{V}_{2Q}) + \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_3} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_3 - \mathbf{V}_{3Q})$$

$$\mathbf{I}_1 - \mathbf{I}_{1Q} = \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_1} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_1 - \mathbf{V}_{1Q}) + \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_2} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_2 - \mathbf{V}_{2Q}) + \frac{\partial \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_3} \Big|_{\bar{\mathbf{v}}=\bar{\mathbf{v}}_Q} (\mathbf{V}_3 - \mathbf{V}_{3Q})$$



Consider now 3 functions each functions of 3 variables

$$I_1 - I_{1Q} = \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_1} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q} (\mathbf{V}_1 - \mathbf{V}_{1Q}) + \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_2} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q} (\mathbf{V}_2 - \mathbf{V}_{2Q}) + \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_3} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q} (\mathbf{V}_3 - \mathbf{V}_{3Q})$$

*Define*

$$\mathbf{y}_{11} = \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_1} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q}$$

$$\mathbf{y}_{12} = \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_2} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q}$$

$$\mathbf{y}_{13} = \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_3} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q}$$

*Recall*

$$\dot{\mathbf{i}}_1 = \mathbf{I}_1 - \mathbf{I}_{1Q}$$

$$\dot{\mathbf{i}}_2 = \mathbf{I}_2 - \mathbf{I}_{2Q}$$

$$\dot{\mathbf{i}}_3 = \mathbf{I}_3 - \mathbf{I}_{3Q}$$

$$\mathbf{u}_1 = \mathbf{V}_1 - \mathbf{V}_{1Q}$$

$$\mathbf{u}_2 = \mathbf{V}_2 - \mathbf{V}_{2Q}$$

$$\mathbf{u}_3 = \mathbf{V}_3 - \mathbf{V}_{3Q}$$

Consider now 3 functions each functions of 3 variables

$$I_1 - I_{1Q} = \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_1} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q} (\mathbf{V}_1 - \mathbf{V}_{1Q}) + \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_2} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q} (\mathbf{V}_2 - \mathbf{V}_{2Q}) + \left. \frac{\partial f_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_3} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q} (\mathbf{V}_3 - \mathbf{V}_{3Q})$$

*Substituting, obtain*

$$\mathbf{i}_1 = y_{11} \mathbf{u}_1 + y_{12} \mathbf{u}_2 + y_{13} \mathbf{u}_3$$

This is now a linear relationship between the small signal electrical variables

Consider now 3 functions each functions of 3 variables

$$\dot{i}_1 = y_{11}u_1 + y_{12}u_2 + y_{13}u_3$$

Lets now extend this to  $I_2$  and  $I_3$

Define 
$$y_{ij} = \left. \frac{\partial f_i(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_j} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q}$$

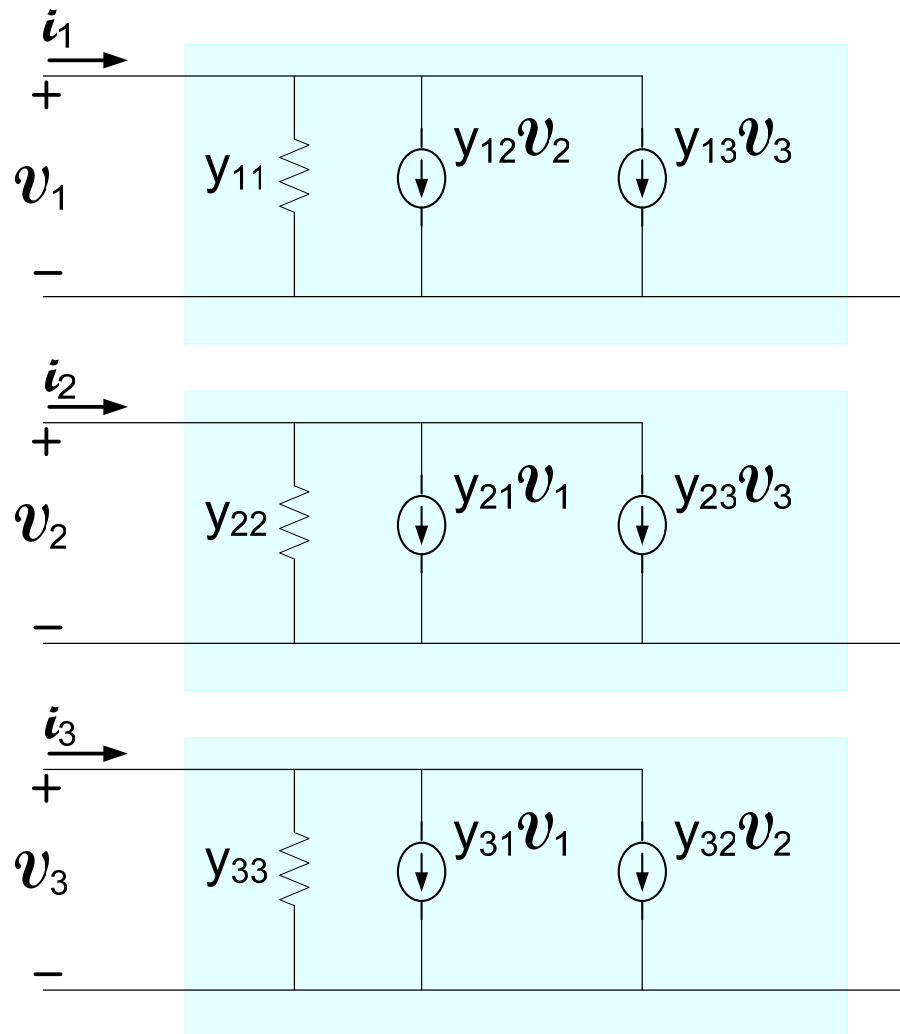
$$\dot{i}_1 = y_{11}u_1 + y_{12}u_2 + y_{13}u_3$$

$$\dot{i}_2 = y_{21}u_1 + y_{22}u_2 + y_{23}u_3$$

$$\dot{i}_3 = y_{31}u_1 + y_{32}u_2 + y_{33}u_3$$

This is a small-signal model of a 4-terminal network and it is linear  
9 small-signal parameters characterize the linear 4-terminal network  
Small-signal model parameters dependent upon Q-point !

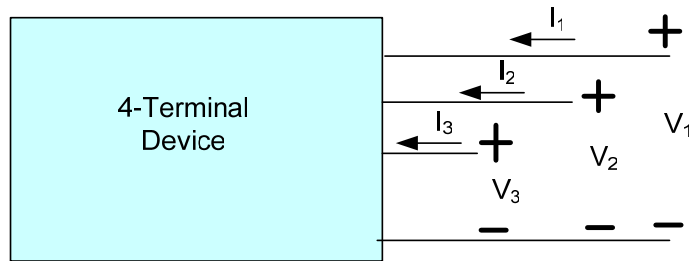
## A small-signal equivalent circuit of a 4-terminal nonlinear network



$$y_{ij} = \left. \frac{\partial f_i(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_j} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q}$$

Equivalent circuit is not unique

## 4-terminal small-signal network summary

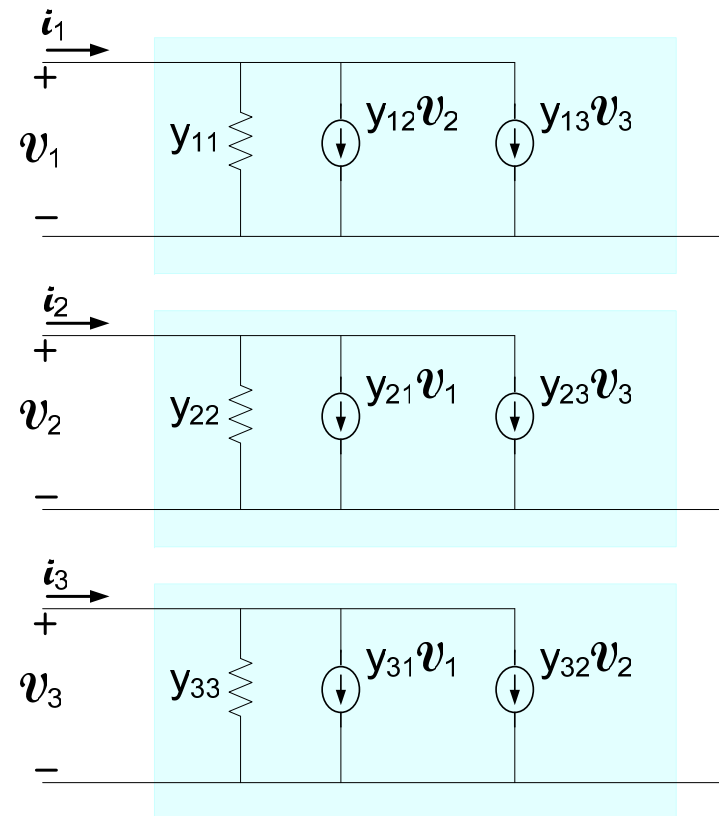


$$\left. \begin{aligned} \mathbf{I}_1 &= \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{I}_2 &= \mathbf{f}_2(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \\ \mathbf{I}_3 &= \mathbf{f}_3(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3) \end{aligned} \right\}$$

### Small signal model:

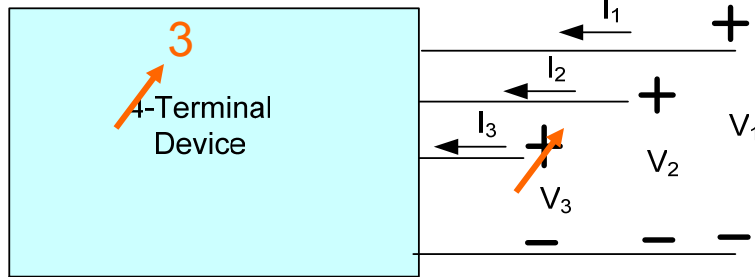
$$\begin{aligned} \mathbf{i}_1 &= y_{11} \mathbf{u}_1 + y_{12} \mathbf{u}_2 + y_{13} \mathbf{u}_3 \\ \mathbf{i}_2 &= y_{21} \mathbf{u}_1 + y_{22} \mathbf{u}_2 + y_{23} \mathbf{u}_3 \\ \mathbf{i}_3 &= y_{31} \mathbf{u}_1 + y_{32} \mathbf{u}_2 + y_{33} \mathbf{u}_3 \end{aligned}$$

$$y_{ij} = \left. \frac{\partial \mathbf{f}_i(\mathbf{V}_1, \mathbf{V}_2, \mathbf{V}_3)}{\partial \mathbf{V}_j} \right|_{\bar{\mathbf{V}} = \bar{\mathbf{V}}_Q}$$



Consider 3-terminal network

# Small-Signal Model



$$\left. \begin{aligned} \dot{i}_1 &= g_1(v_1, v_2, v_3) \\ \dot{i}_2 &= g_2(v_1, v_2, v_3) \\ \dot{i}_3 &= g_3(v_1, v_2, v_3) \end{aligned} \right\}$$

$$\dot{i}_1 = y_{11}v_1 + y_{12}v_2 + y_{13}v_3$$

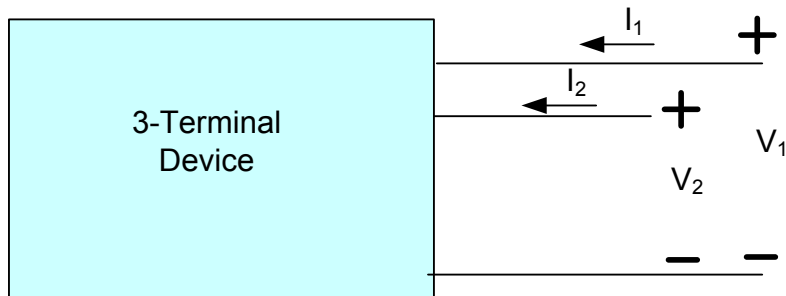
$$\dot{i}_2 = y_{21}v_1 + y_{22}v_2 + y_{23}v_3$$

$$\dot{i}_3 = y_{31}v_1 + y_{32}v_2 + y_{33}v_3$$

$$y_{ij} = \left. \frac{\partial f_i(v_1, v_2, v_3)}{\partial v_j} \right|_{\bar{v} = \bar{v}_Q}$$

Consider 3-terminal network

# Small-Signal Model



$$\left. \begin{aligned} I_1 &= f_1(V_1, V_2) \\ I_2 &= f_2(V_1, V_2) \end{aligned} \right\}$$

Define

$$i_1 = I_1 - I_{1Q}$$

$$u_1 = V_1 - V_{1Q}$$

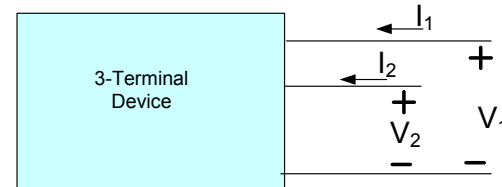
$$i_2 = I_2 - I_{2Q}$$

$$u_2 = V_2 - V_{2Q}$$

Small signal model is that which represents the relationship between the small signal voltages and the small signal currents

Consider 3-terminal network

# Small-Signal Model

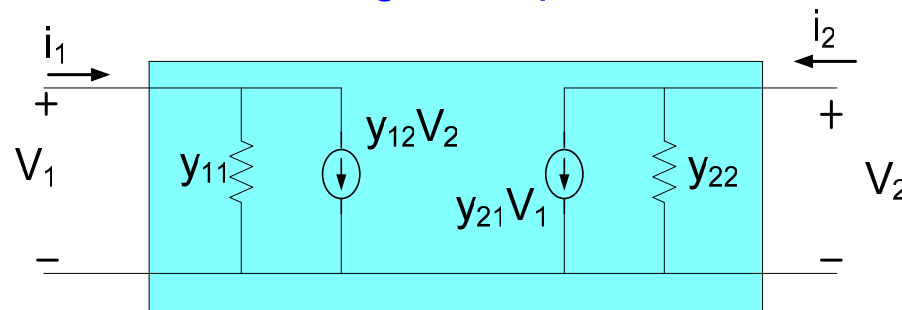


$$\begin{aligned} i_1 &= y_{11} v_1 + y_{12} v_2 \\ i_2 &= y_{21} v_1 + y_{22} v_2 \end{aligned}$$

$$y_{ij} = \left. \frac{\partial f_i(\mathbf{V}_1, \mathbf{V}_2)}{\partial V_j} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q}$$

$$\bar{\mathbf{V}} = \begin{pmatrix} V_{1Q} \\ V_{2Q} \end{pmatrix}$$

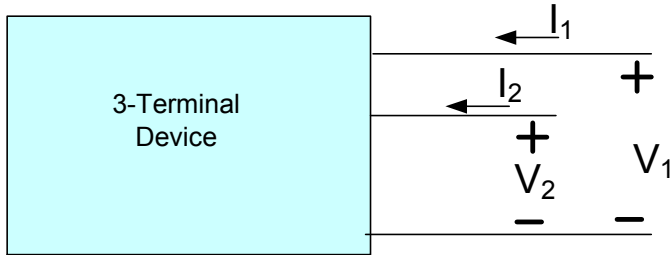
A Small Signal Equivalent Circuit



4 small-signal parameters characterize this 3-terminal (two-port) linear network  
 Small signal parameters dependent upon Q-point



### 3-terminal small-signal network summary

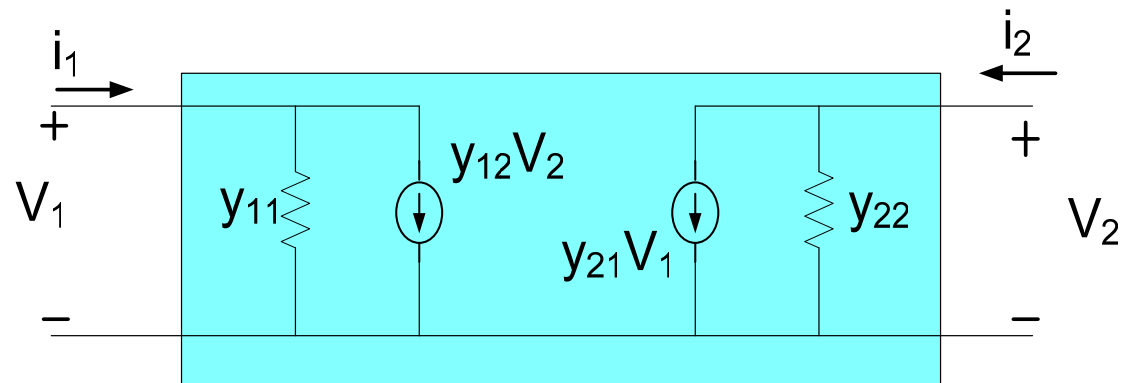


$$\left. \begin{aligned} \mathbf{I}_1 &= \mathbf{f}_1(\mathbf{V}_1, \mathbf{V}_2) \\ \mathbf{I}_2 &= \mathbf{f}_2(\mathbf{V}_1, \mathbf{V}_2) \end{aligned} \right\}$$

### Small signal model:

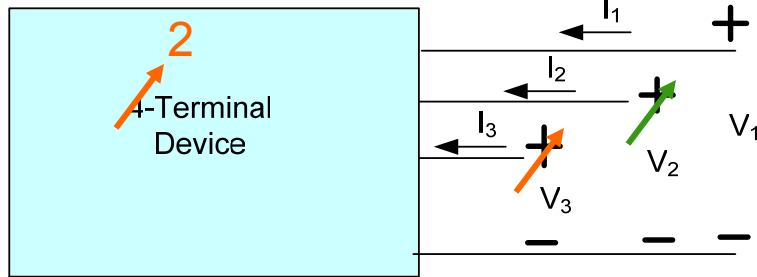
$$\begin{aligned} \mathbf{i}_1 &= y_{11} \mathbf{v}_1 + y_{12} \mathbf{v}_2 \\ \mathbf{i}_2 &= y_{21} \mathbf{v}_1 + y_{22} \mathbf{v}_2 \end{aligned}$$

$$\mathbf{y}_{ij} = \left. \frac{\partial \mathbf{f}_i(\mathbf{V}_1, \mathbf{V}_2)}{\partial \mathbf{V}_j} \right|_{\bar{\mathbf{v}} = \bar{\mathbf{v}}_Q}$$



Consider 2-terminal network

# Small-Signal Model



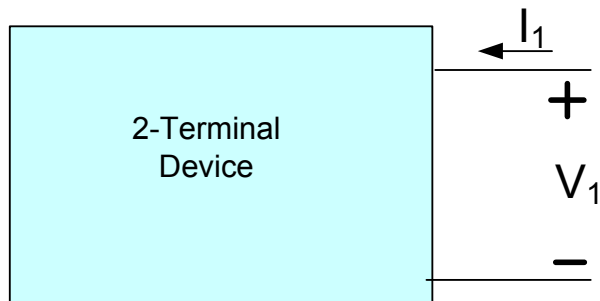
$$\left. \begin{aligned} \dot{i}_1 &= g_1(v_1, v_2, v_3) \\ \dot{i}_2 &= g_2(v_1, v_2, v_3) \\ \dot{i}_3 &= g_3(v_1, v_2, v_3) \end{aligned} \right\}$$

$$\begin{aligned} \dot{i}_1 &= y_{11}v_1 + y_{12}v_2 + y_{13}v_3 \\ \dot{i}_2 &= y_{21}v_1 + y_{22}v_2 + y_{23}v_3 \\ \dot{i}_3 &= y_{31}v_1 + y_{32}v_2 + y_{33}v_3 \end{aligned}$$

$$y_{ij} = \left. \frac{\partial f_i(v_1, v_2, v_3)}{\partial v_j} \right|_{\bar{v} = \bar{v}_Q}$$

Consider 2-terminal network

# Small-Signal Model



$$I_1 = f_1(V_1)$$

Define

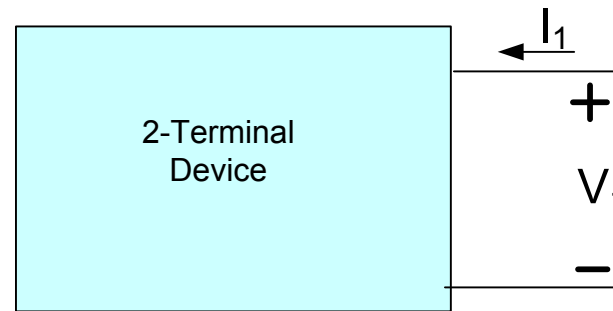
$$i_1 = I_1 - I_{1Q}$$

$$v_1 = V_1 - V_{1Q}$$

Small signal model is that which represents the relationship between the small signal voltages and the small signal currents

Consider 2-terminal network

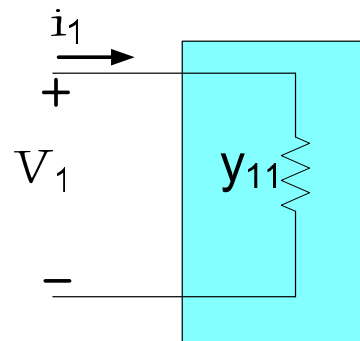
# Small-Signal Model



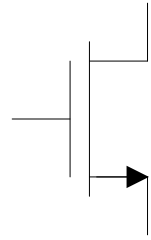
$$\mathbf{i}_1 = y_{11} \mathbf{v}_1$$

$$y_{11} = \left. \frac{\partial f_1(V_1)}{\partial V_1} \right|_{\bar{V} = \bar{V}_Q} \quad \bar{V} = V_{1Q}$$

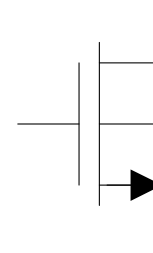
A Small Signal Equivalent Circuit



# Small Signal Model of MOSFET



*3-terminal device*

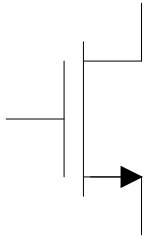


*4-terminal device*

*MOSFET is actually a 4-terminal device but for many applications acceptable predictions of performance can be obtained by treating it as a 3-terminal device by neglecting the bulk terminal*

*In this course, we have been treating it as a 3-terminal device and in this lecture will develop the small-signal model by treating it as a 3-terminal device*

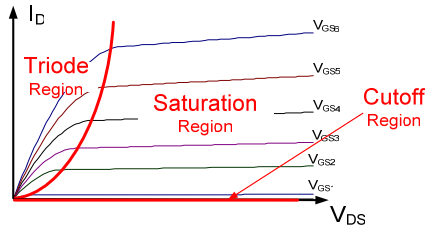
# Small Signal Model of MOSFET



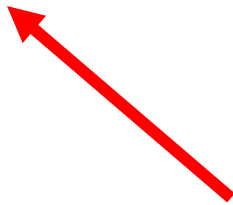
Large Signal Model

$$I_G = 0$$

3-terminal device



$$I_D = \begin{cases} 0 & V_{GS} \leq V_T \\ \mu C_{OX} \frac{W}{L} \left( V_{GS} - V_T - \frac{V_{DS}}{2} \right) V_{DS} & V_{GS} \geq V_T, V_{DS} < V_{GS} - V_T \\ \mu C_{OX} \frac{W}{2L} (V_{GS} - V_T)^2 (1 + \lambda V_{DS}) & V_{GS} \geq V_T, V_{DS} \geq V_{GS} - V_T \end{cases}$$



*MOSFET is usually operated in saturation region in linear applications where a small-signal model is needed so will develop the small-signal model in the saturation region*

# Small Signal Model of MOSFET

$$I_1 = f_1(V_1, V_2) \quad \longleftrightarrow \quad I_G = 0$$

$$I_2 = f_2(V_1, V_2) \quad \longleftrightarrow \quad I_D = \mu C_{\text{ox}} \frac{W}{2L} (V_{\text{GS}} - V_{\text{T}})^2 (1 + \lambda V_{\text{DS}})$$

*Small-signal model:*

$$y_{ij} = \left. \frac{\partial f_i(V_1, V_2)}{\partial V_j} \right|_{\bar{V}=\bar{V}_Q}$$

$$y_{11} = \left. \frac{\partial I_G}{\partial V_{\text{GS}}} \right|_{\bar{V}=\bar{V}_Q}$$

$$y_{12} = \left. \frac{\partial I_G}{\partial V_{\text{DS}}} \right|_{\bar{V}=\bar{V}_Q}$$

$$y_{21} = \left. \frac{\partial I_D}{\partial V_{\text{GS}}} \right|_{\bar{V}=\bar{V}_Q}$$

$$y_{22} = \left. \frac{\partial I_D}{\partial V_{\text{DS}}} \right|_{\bar{V}=\bar{V}_Q}$$

# Small Signal Model of MOSFET

$$I_1 = f_1(V_1, V_2) \quad \longleftrightarrow \quad I_G = 0$$

$$I_2 = f_2(V_1, V_2) \quad \longleftrightarrow \quad I_D = \mu C_{\text{ox}} \frac{W}{2L} (V_{\text{GS}} - V_{\text{T}})^2 (1 + \lambda V_{\text{DS}})$$

*Small-signal model:*

$$y_{11} = \left. \frac{\partial I_G}{\partial V_{\text{GS}}} \right|_{\bar{V}=\bar{V}_Q} = 0$$

$$y_{12} = \left. \frac{\partial I_G}{\partial V_{\text{DS}}} \right|_{\bar{V}=\bar{V}_Q} = 0$$

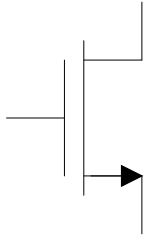
$$y_{21} = \left. \frac{\partial I_D}{\partial V_{\text{GS}}} \right|_{\bar{V}=\bar{V}_Q} = 2\mu C_{\text{ox}} \frac{W}{2L} (V_{\text{GS}} - V_{\text{T}})' (1 + \lambda V_{\text{DS}}) \Big|_{\bar{V}=\bar{V}_Q} = \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_{\text{T}}) (1 + \lambda V_{\text{DSQ}})$$

$$y_{21} \cong \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_{\text{T}})$$

$$y_{22} = \left. \frac{\partial I_D}{\partial V_{\text{DS}}} \right|_{\bar{V}=\bar{V}_Q} = \mu C_{\text{ox}} \frac{W}{2L} (V_{\text{GS}} - V_{\text{T}})^2 \lambda \Big|_{\bar{V}=\bar{V}_Q} \cong \lambda I_{\text{DQ}}$$

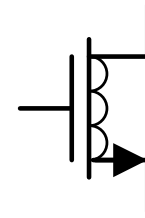


# Small Signal Model of MOSFET



$$I_G = 0$$

$$I_D = \mu C_{\text{OX}} \frac{W}{2L} (V_{\text{GS}} - V_T)^2 (1 + \lambda V_{\text{DS}})$$



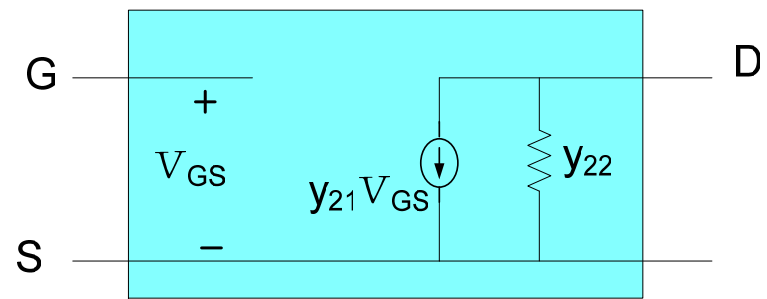
$$y_{12} = 0$$

$$y_{11} = 0$$

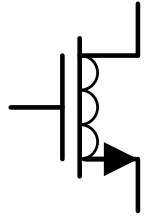
$$y_{21} \cong \mu C_{\text{OX}} \frac{W}{L} (V_{\text{GSQ}} - V_T)$$

$$y_{22} \cong \lambda I_{\text{DQ}}$$

$$\begin{aligned} i_G &= y_{11} v_{\text{GS}} + y_{12} v_{\text{DS}} \\ i_D &= y_{21} v_{\text{GS}} + y_{22} v_{\text{DS}} \end{aligned}$$



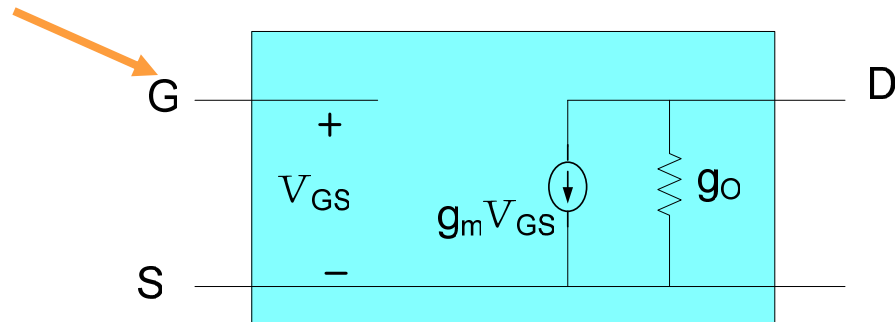
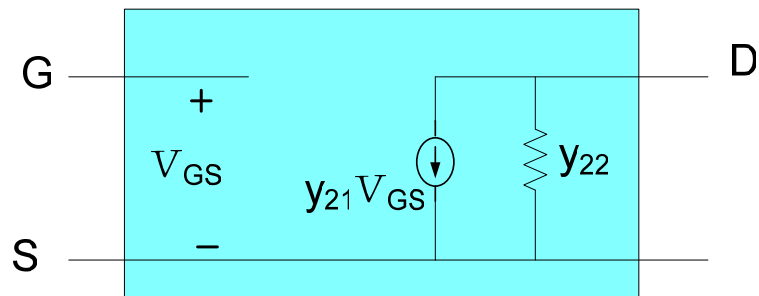
# Small Signal Model of MOSFET



by convention,  $y_{21}=g_m$ ,  $y_{22}=g_o$

$$\therefore y_{21} \cong g_m = \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_T)$$

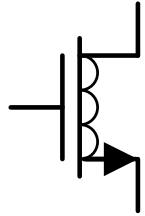
$$y_{22} = g_o \cong \lambda I_{\text{DQ}}$$



$$i_G = 0$$

$$i_D = g_m v_{GS} + g_o v_{DS}$$

# Small Signal Model of MOSFET

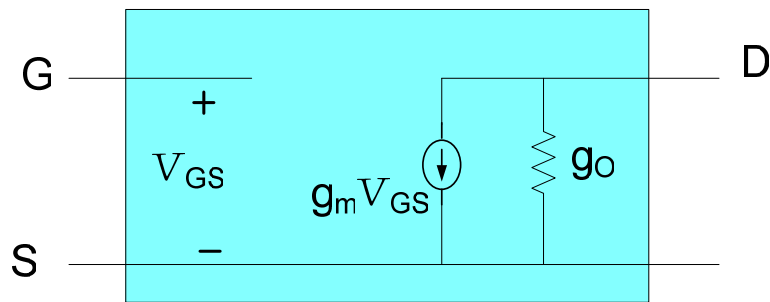


by convention,  $y_{21} = g_m$ ,  $y_{22} = g_o$

$$\therefore y_{21} \cong g_m = \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_T)$$

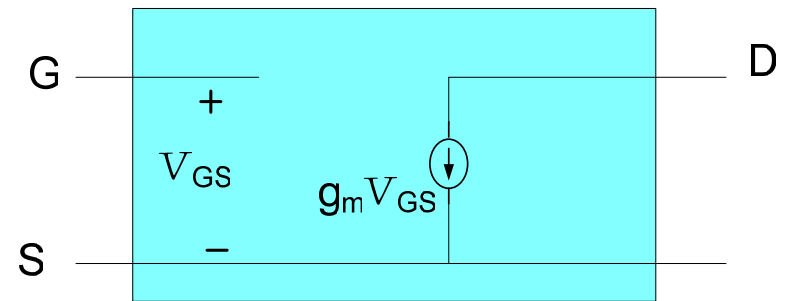
$$y_{22} = g_o \cong \lambda I_{\text{DQ}}$$

Often it can be assumed that  $\lambda = 0$



$$i_G = 0$$

$$i_D = g_m v_{GS} + g_o v_{DS}$$

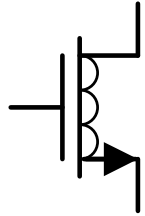


$$i_G = 0$$

$$i_D = g_m v_{GS}$$

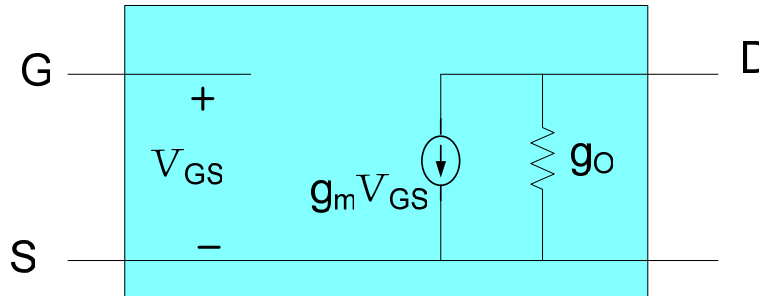
*Simplified small signal MOSFET model with  $\lambda = 0$*

# Small Signal Model of MOSFET



$$g_m = \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_T)$$

$$g_o \cong \lambda I_{\text{DQ}}$$



*Alternate equivalent  $g_m$  expressions:*

$$I_{\text{DQ}} \cong \mu C_{\text{ox}} \frac{W}{2L} (V_{\text{GSQ}} - V_T)^2$$

$$g_m = \mu C_{\text{ox}} \frac{W}{L} (V_{\text{GSQ}} - V_T)$$

$$g_m = \sqrt{2\mu C_{\text{ox}} \frac{W}{L}} \cdot \sqrt{I_{\text{DQ}}}$$

$$g_m = \frac{2I_{\text{DQ}}}{V_{\text{GSQ}} - V_T}$$

**End of Lecture 33**